Product data sheet

1. General description

N-channel enhancement mode Field-Effect Transistor (FET) in a medium power SOT223 (SC-73) Surface-Mounted Device (SMD) plastic package using Trench MOSFET technology.

2. Features and benefits

- Logic level compatible
- Very fast switching
- Trench MOSFET technology
- ElectroStatic Discharge (ESD) protection > 2 kV HBM
- AEC-Q101 qualified

3. Applications

- Relay driver
- · LED backlight driver
- Low-side loadswitch
- Switching circuits

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V_{DS}	drain-source voltage	T _j = 25 °C		-	-	100	V
V_{GS}	gate-source voltage			-20	-	20	V
I _D	drain current	V _{GS} = 10 V; T _{amb} = 25 °C	[1]	-	-	1.5	Α
Static characte	Static characteristics						
R _{DSon}	drain-source on-state resistance	$V_{GS} = 10 \text{ V}; I_D = 1.5 \text{ A}; T_j = 25 ^{\circ}\text{C}$		-	285	385	mΩ

^[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and mounting pad for drain 6 cm².



5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	G	gate	4	D I
2	D	drain		
3	S	source		G T
4	D	drain	⊟1 ⊟2 ⊟3 SC-73 (SOT223)	S 017aaa255

6. Ordering information

Table 3. Ordering information

Table of Cracing II						
Type number	Package	ge				
	Name	Description	Version			
PMT280ENEA	SC-73	plastic surface-mounted package with increased heatsink; 4 leads	SOT223			

7. Marking

Table 4. Marking codes

Type number	Marking code
PMT280ENEA	28ENEA

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V _{DS}	drain-source voltage	T _j = 25 °C		-	100	V
V_{GS}	gate-source voltage	-		-20	20	V
I _D	drain current	V _{GS} = 10 V; T _{amb} = 25 °C	[1]	-	1.5	Α
		V _{GS} = 10 V; T _{amb} = 100 °C	[1]	-	1	Α
I _{DM}	peak drain current	T_{amb} = 25 °C; single pulse; $t_p \le 10$ μs		-	6	Α
E _{DS(AL)S}	non-repetitive drain-source avalanche energy	$T_{j(init)}$ = 25 °C; I_D = 0.16 A; DUT in avalanche (unclamped)		-	8.4	mJ
P _{tot}	total power dissipation	T _{amb} = 25 °C	[2]	-	770	mW
			[1]	-	1.92	W
		T _{sp} = 25 °C		-	6.25	W
Tj	junction temperature			-55	150	°C
T _{amb}	ambient temperature			-55	150	°C
T _{stg}	storage temperature			-65	150	°C
Source-dra	in diode			'		
Is	source current	T _{amb} = 25 °C	[1]	-	1.5	Α
ESD maxim	num rating		'			,
V _{ESD}	electrostatic discharge voltage	НВМ	[3]	-	2000	V

^[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and mounting pad for drain 6 cm².

^[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

^[3] Measured between all pins.

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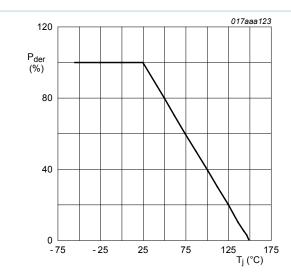


Fig. 1. Normalized total power dissipation as a function of junction temperature

$$P_{der} = \frac{P_{tot}}{P_{tot(25^{\circ}C)}} \times 100 \%$$

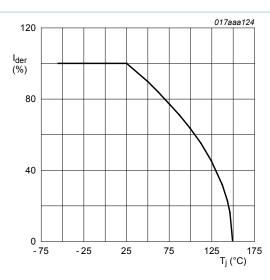


Fig. 2. Normalized continuous drain current as a function of junction temperature

$$I_{der} = \frac{I_D}{I_{D(25^{\circ}C)}} \times 100 \%$$

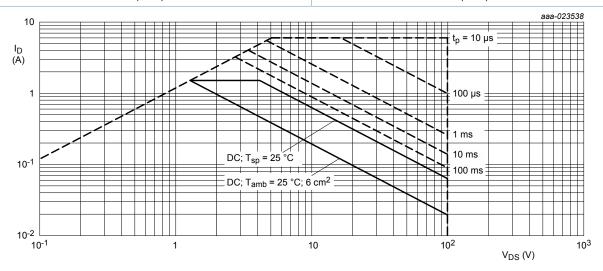


Fig. 3. Safe operating area; junction to ambient; continuous and peak drain currents as a function of drainsource voltage

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Thermal characteristics

Table 6. **Thermal characteristics**

PMT280ENEA

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R _{th(j-a)}	thermal resistance from junction to ambient	in free air	[1]	-	141	162	K/W
			[2]	-	56	65	K/W
R _{th(j-sp)}	thermal resistance from junction to solder point			-	10	20	K/W

- Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- Device mounted on an FR4 PCB, single-sided copper, tin-plated and mounting pad for drain 6 cm².

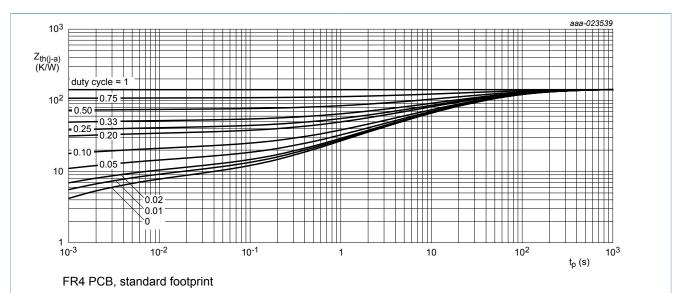


Fig. 4. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

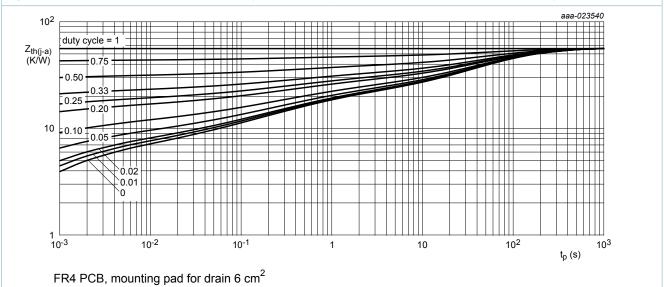


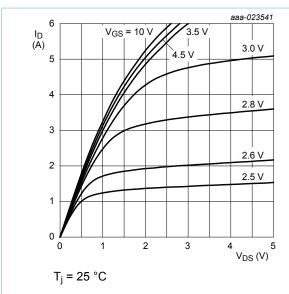
Fig. 5. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

10. Characteristics

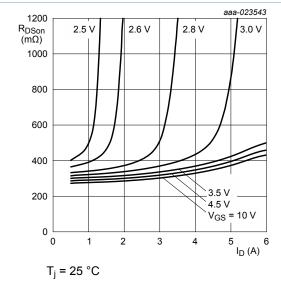
Table 7 Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static char	acteristics					
$V_{(BR)DSS}$	drain-source breakdown voltage	I _D = 250 μA; V _{GS} = 0 V; T _j = 25 °C	100	-	-	V
V_{GSth}	gate-source threshold voltage	$I_D = 250 \ \mu A; \ V_{DS} = V_{GS}; \ T_j = 25 \ ^{\circ}C$	1.3	1.7	2.7	V
I _{DSS}	drain leakage current	V _{DS} = 100 V; V _{GS} = 0 V; T _j = 25 °C	-	-	1	μA
I _{GSS}	gate leakage current	V _{GS} = 20 V; V _{DS} = 0 V; T _j = 25 °C	-	-	15	μA
		V _{GS} = -20 V; V _{DS} = 0 V; T _j = 25 °C	-	-	-15	μA
		V _{GS} = 10 V; V _{DS} = 0 V; T _j = 25 °C	-	-	1	μA
		V _{GS} = -10 V; V _{DS} = 0 V; T _j = 25 °C	-	-	-1	μA
200	drain-source on-state	V _{GS} = 10 V; I _D = 1.5 A; T _j = 25 °C	-	285	385	mΩ
	resistance	V _{GS} = 10 V; I _D = 1.5 A; T _j = 150 °C	-	627	847	mΩ
		V_{GS} = 4.5 V; I_D = 1.4 A; T_j = 25 °C	-	301	432	mΩ
9 _{fs}	forward transconductance	$V_{DS} = 10 \text{ V}; I_D = 1.5 \text{ A}; T_j = 25 \text{ °C}$	-	5.4	-	S
R _G	gate resistance	f = 1 MHz	-	2.2	-	Ω
Dynamic c	haracteristics				'	,
Q _{G(tot)}	total gate charge	V_{DS} = 50 V; I_{D} = 1.5 A; V_{GS} = 10 V;	-	4.5	6.8	nC
Q_{GS}	gate-source charge	T _j = 25 °C	-	0.4	-	nC
Q_{GD}	gate-drain charge		-	1	-	nC
C _{iss}	input capacitance	$V_{DS} = 50 \text{ V}; f = 1 \text{ MHz}; V_{GS} = 0 \text{ V};$	-	195	-	pF
C _{oss}	output capacitance	T _j = 25 °C	-	13	-	pF
C _{rss}	reverse transfer capacitance		-	9	-	pF
t _{d(on)}	turn-on delay time	V _{DS} = 50 V; I _D = 1.5 A; V _{GS} = 10 V;	-	5	-	ns
t _r	rise time	$R_{G(ext)} = 6 \Omega$; $T_j = 25 °C$	-	7	-	ns
$t_{d(off)}$	turn-off delay time		-	9	-	ns
t _f	fall time		-	2	-	ns
Source-dra	ain diode	1	1			
V_{SD}	source-drain voltage	I _S = 1.5 A; V _{GS} = 0 V; T _i = 25 °C	_	0.9	1.2	V

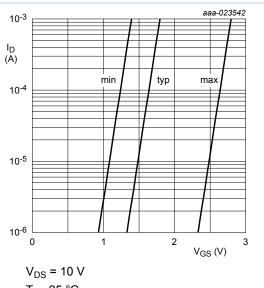
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Output characteristics: drain current as a Fig. 6. function of drain-source voltage; typical values



Drain-source on-state resistance as a function Fig. 8. of drain current; typical values



 $T_i = 25 \, ^{\circ}C$

Fig. 7. Subthreshold drain current as a function of gate-source voltage

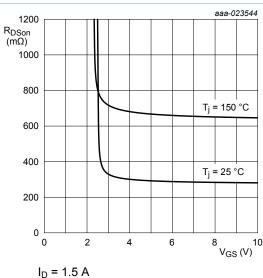


Fig. 9. Drain-source on-state resistance as a function of gate-source voltage; typical values

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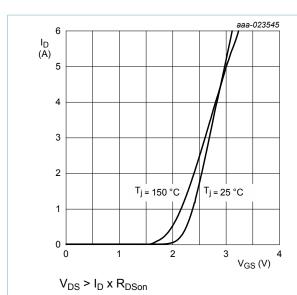


Fig. 10. Transfer characteristics: drain current as a function of gate-source voltage; typical values

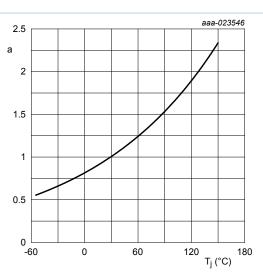


Fig. 11. Normalized drain-source on-state resistance as a function of junction temperature; typical values

$$a = \frac{R_{DSon}}{R_{DSon(25^{\circ}C)}}$$

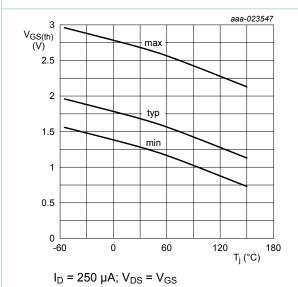
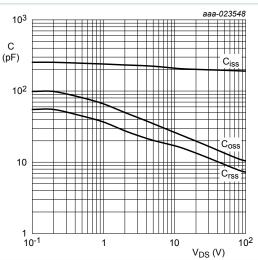


Fig. 12. Gate-source threshold voltage as a function of junction temperature



 $f = 1 MHz; V_{GS} = 0 V$

Fig. 13. Input, output and reverse transfer capacitances as a function of drain-source voltage; typical values

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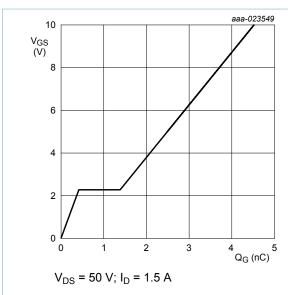


Fig. 14. Gate-source voltage as a function of gate charge; typical values

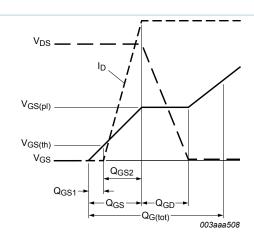


Fig. 15. Gate charge waveform definitions

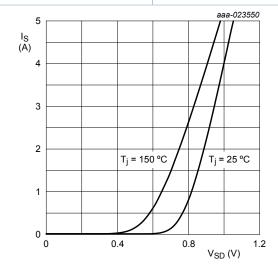
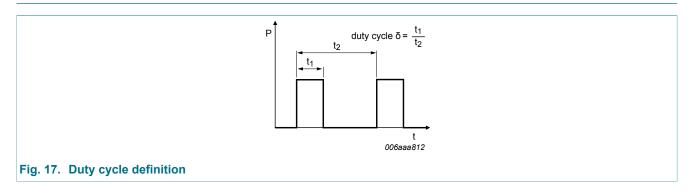


Fig. 16. Source current as a function of source-drain voltage; typical values

 $V_{GS} = 0 V$

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11. Test information



11.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - Stress test qualification for discrete semiconductors, and is suitable for use in automotive applications.

12. Package outline

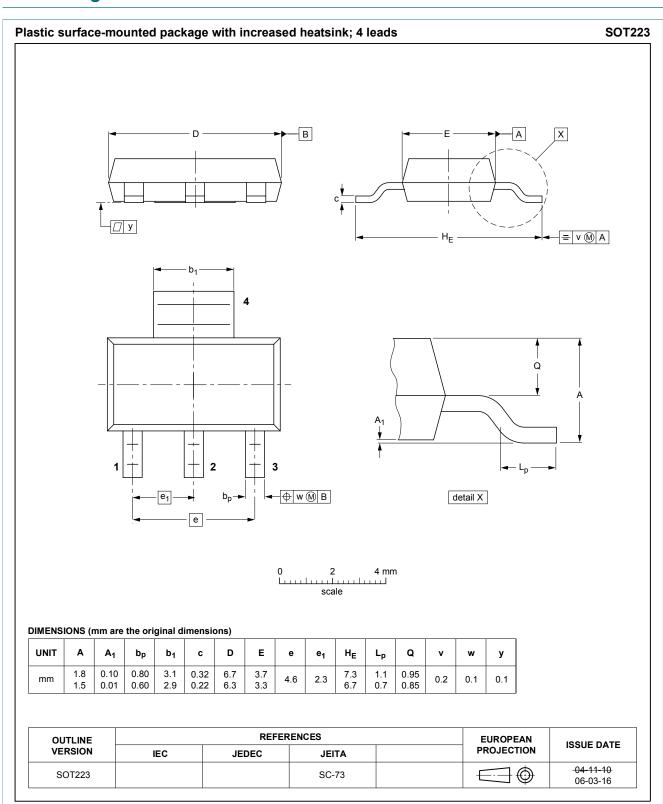
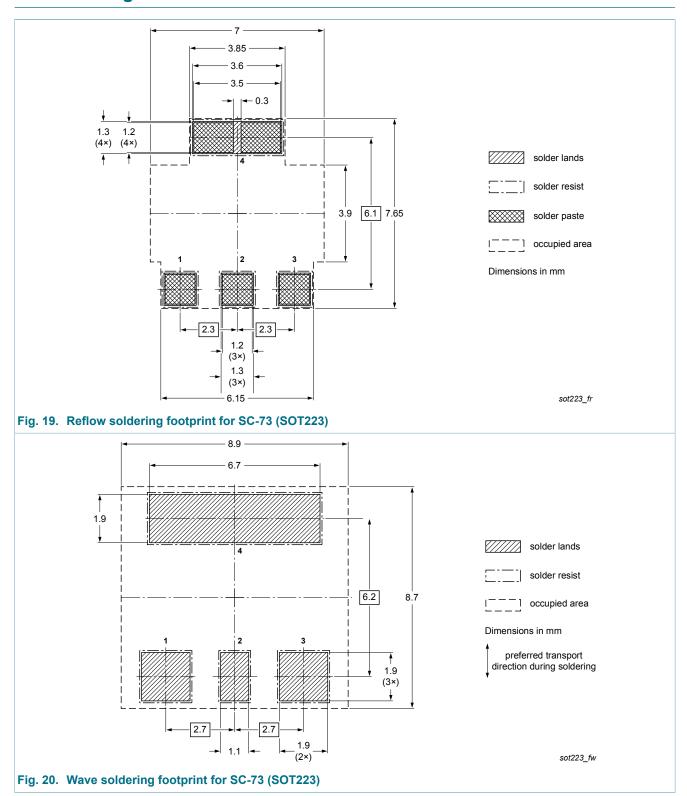


Fig. 18. Package outline SC-73 (SOT223)

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13. Soldering



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14. Revision history

Table 8. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
PMT280ENEA v.1	20160714	Product data sheet	-	-

15. Legal information

15.1 Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
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PMT280ENEA

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